### **Electric permittivity of the vacuum in a strong constant electric field**

### **Hidetoshi Taya**

#### ( Keio U. )

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### **This talk**

#### Discuss the electric permittivity  $\epsilon$  of the vacuum **in a strong constant electric field**



- $\epsilon$  is no longer a const.  $\epsilon = \epsilon(\bar{E})$  due to the vacuum polarization
- ・many studies since the early days, but is still worthwhile to be investigated  $\Rightarrow$  3 motivations [Heisenberg-Euler (1936)] [Toll 1952] [Klein-Nigam (1964)] [Baier-Breitenlohner (1967)] … Review: [King-Heinzl (2015)] [Ejlli et al. (PVLAS) (2020)] [Fedotov et al. (2023)] …

#### **(1) The current understanding is limited to weak/slow regime**

The most famous formula = based on Euler-Heisenberg Lagrangian

$$
\mathcal{D} = -\frac{\partial \mathcal{L}_{EH}}{\partial \mathcal{E}} \qquad \Rightarrow \qquad \epsilon = \frac{\alpha}{45\pi} \left(\frac{e\bar{E}}{m^2}\right)^2 \times \begin{cases} 6 & (\parallel) \\ 2 & (\perp) \end{cases}
$$
 [Baier-Breitenlohner (1967)]

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[Baier-Breitenlohner (1967)]

#### **<u>Problem 1: Valid only in the weak limit**  $e\overline{E} \ll m^2$ **</u>**

power corrections could be included  $(e\bar{E})^n$ , but

- $\cdot$  is factorially divergent  $\Rightarrow$  does not necessarily improve the formula
- non-pert. factor like  $e^{1/e\bar{E}}$  can never be included  $\text{cf. [Heinzl-Schroder (2006)]}$

#### **Problem 2: Valid only in the slow limit**  $\omega \ll m$

- $\cdot$  not possible to discuss  $\omega$  dependence
- the physics must be different above the pair-production threshold  $\omega > 2m$

#### **Problem 3: Neglecting the imaginary part Im**  $\mathcal{L}_{EH}$

- $\epsilon$  (in the coordinate space) must be real, so one must set Im  $\mathcal{L}_{\rm Euler-Heisenberg}$
- $\Rightarrow$  pair production and "non-equilibrium-ness" of E field are completely dismissed

#### **Q: What happens if I go beyond those limitations ?**









cf. [King-Heinzl-Blackburn (2023)]

#### **(2) As a signature of non-trivial QED vacuum structure in E field**

The QED vacuum (= the Dirac sea) has a non-trivial electron dist. in an E field, which can leave observable imprints

**QED vacuum at**  $\overline{E} = 0$ 

 $\leftarrow$  positive energy states

← mass gap ~ 2m

← Dirac sea

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#### **Q: What happens to the electric permittivity ?**

Note: The motivation (1) (in particular, going beyond  $\omega \ll m$ ) is important to achieve this

#### **(3) Pursue analogy between strong-field QED and semicond. phys**

- ・ Ground-state structure of semicond. = The QED vacuum
	- ⇒ the QED vacuum should response against external field in a similar way to a semiconductor and vice versa

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- ・ Ground-state structure of semicond. = The QED vacuum
	- ⇒ the QED vacuum should response against external field in a similar way to a semiconductor and vice versa
- Nontrivial oscillating change in  $\epsilon$  (i.e., motivation (2)) has already been observed more than 50 yrs ago in semicond. physics ! (⇒ the Franz-Keldysh effect and electroreflectance) [Franz (1958)] [Keldysh (1958)]



**Q: Natural to expect this change in QED. Is this analogy true ?**

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**II. Theory** Linear response theory based on in-in formalism of QFT

**III. Results** will give positive statements to the motivations (1) - (3)

### **IV. Summary**

#### **Linear response theory based on in-in formalism of QFT**

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**Step 1**: Definitions of  $D$  and  $\epsilon$ 

• Total flux 
$$
D = E + P(\overline{E}, \mathcal{E}) = E + P_0(\overline{E}) + P_1(\overline{E})\mathcal{E} + \cdots
$$
  
\n
$$
= \overline{E} + P_0(\overline{E}) + \frac{1}{2}(1 + P_1(\overline{E}))\mathcal{E} + \cdots \implies \epsilon = 1 + P_1(\overline{E})
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**Step 2:** Calculate  $P_1$ 

• Ampere law: 
$$
-\dot{P} = J = \langle 0; \text{in} | \bar{\psi}(\bar{E}, \mathcal{E}) \gamma^{\mu} \psi(\bar{E}, \mathcal{E}) | 0; \text{in} \rangle
$$
  
\n
$$
= \langle 0; \text{in} | \bar{\psi}_0(\bar{E}) \gamma^{\mu} \psi_0(\bar{E}) | 0; \text{in} \rangle
$$
\n
$$
+ \frac{1}{2} \langle 0; \text{in} | \bar{\psi}_1(\bar{E}) \gamma^{\mu} \psi_0(\bar{E}) + \bar{\psi}_0(\bar{E}) \gamma^{\mu} \psi_1(\bar{E}) | 0; \text{in} \rangle \times \mathcal{E} + \mathcal{O}(\mathcal{E}^2)
$$

- ・Not in-out amplitude, but in-in ! cf. [Copinger-Fukushima-Shi (2018)]
	- $\Rightarrow$  crucial when pair creating (or in non-equil.):  $|0; \text{out}\rangle = |0; \text{in}\rangle + (\text{pair states like } |e^+e^-; \text{in}\rangle)$
- Diagrammatically, evaluate

**Detail 1:** Loop diagram ⇒ UV divergent ⇒ use Kramers-Kronig relation

[Toll (1960)] [Heinzl, Schroeder (2006)] [Borysov et al. (2022)]

2

 $Im \bullet =$ 

Causality ⇒ Re 
$$
\epsilon(\omega) = \frac{1}{\pi}
$$
P. V.  $\int_{-\infty}^{+\infty} d\omega' \frac{1}{\omega' - \omega} Im \epsilon(\omega')$ 

⇒ sufficient to calculate the imaginary part (same approach has been adopted in semicond.) [Aspnes(1967)]

**Detail 1:** Loop diagram ⇒ UV divergent ⇒ use Kramers-Kronig relation



**Detail 2:** Im  $\epsilon$  is directly related to the (dynamically-assisted) Schwinger effect

- ・Electromagnetism tells us: Im  $\epsilon$  is related to the dielectric energy loss See, e.g., textbook by Landau-Lefshitz
- ・ Energy loss of probe due to the pair prod.
- ・ Microscopically, the dielectric energy loss should be caused by the pair prod.

$$
\frac{dU_1}{dt} = \mathcal{E}\frac{d\mathcal{D}}{dt} = \frac{1}{2}\omega\mathcal{E}^2 \text{ Im }\epsilon
$$

$$
\frac{dU_2}{dt} = \omega\frac{N(\mathcal{E} \neq 0) - N(\mathcal{E} = 0)}{VT}
$$

$$
U_1 = U_2 \implies \frac{N(\mathcal{E} \neq 0) - N(\mathcal{E} = 0)}{VT} = \frac{1}{2} \mathcal{E}^2 \text{ Im } \epsilon
$$

∴ Schwinger  $\leftrightarrow$  Im  $\epsilon \leftrightarrow$  Re  $\epsilon \Rightarrow$   $\epsilon$  as an indirect sign. of Schwinger & vice versa **KK**

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### **Results (1/3): Imaginary part of**



・ Oscillation, as expected from the tilted vacuum



- ・ Essentially the same pattern as semi-conductor observation
- Birefringent (Im  $\Delta \epsilon_{\parallel} \neq$  Im  $\Delta \epsilon_{\perp}$ ) but the basically the same
- Non-vanishing even at  $\omega \rightarrow 0$  due to the strong-field non-perturbative effect A simple explanation: In the slow limit, the standard Schwinger formula is valid  $\Rightarrow$  Im  $\epsilon \propto (N_{\text{Schwinger}}(\bar{E} + \mathcal{E}) - N_{\text{Schwinger}}(\bar{E})) \propto (\exp \left[-\pi \frac{m^2}{e(E + \mathcal{E})}\right]$  $\left[\frac{m^2}{e(E+\varepsilon)}\right]$  — exp $\left[-\pi\frac{m^2}{e\bar{E}}\right]$  $\frac{m^2}{e\bar{E}}$ ]) = (finite) × exp $\left[-\pi \frac{m^2}{e\bar{E}}\right]$  $e\bar{E}$

### **Results (2/3): Real part of**



- ・ Oscillation, consistent with semi-conductor
- Logarithmically divergent at  $\omega \rightarrow 0$ due to the non-perturbative effect

$$
\therefore \quad \text{Re } \epsilon(0) = \frac{1}{\pi} \text{P.V.} \int_{-\infty}^{+\infty} d\omega' \frac{1}{\omega'} \text{Im } \epsilon(\omega')
$$

$$
\sim \frac{1}{\pi} \int_{-\infty}^{+\infty} d\omega' \frac{1}{\omega'} \text{Im } \epsilon(0) \sim (\log \text{div.}) \times \exp\left[-\pi \frac{m^2}{e\overline{E}}\right]
$$



### **Results (3/3): Comparison w/ EH**



- After the log subtraction, the result is consistent with the EH result  $\Delta \epsilon_{\text{EH}} =$  $\alpha$  $45\pi$  $e\bar{E}$  $m<sup>2</sup>$ 2  $\times \}$ 6 (∥) 2 (⊥)
- Significant deviation for finite  $\omega$  and/or stronger  $\bar{E}$

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### **Summary**

#### Discussed the electric permittivity  $\epsilon$  of the vacuum **in a strong constant electric field**

#### **Three motivations and my answers to them:**

(2) As a signature of non-trivial QED vacuum structure in E field (3) Pursue analogy between strong-field QED and semicond. phys **Motivations:** (1) The current understanding is limited to weak/slow regime

(1): Succeeded with a linear response theory based on in-in formalism (2)&(3): Yes, a characteristic oscillating structure in  $\epsilon$ , similarly to semicond. **Answers:**



#### **Other lessons (and further comments)**

• Higher frequency gives a bigger signal of  $\epsilon$  (or vacuum birefringence, in general) e.g. peak at  $\omega \sim 2m$ : Re $\Delta \epsilon_{\parallel} \approx (-1.4 \times 10^{-4}) \times \left( \frac{1}{1 \times 10^{23} \text{ W/cm}^2} \right)$   $\gg \Delta \epsilon_{\text{EH}} = O(10^{-7})$  for  $I = O(1 \times 10^{23} \text{ W/cm}^2)$ (PW laser)

Need to go beyond EH for large  $\omega$  or strong  $\bar{E} \Rightarrow$  implications to heavy-ion coll., magnetar, ...?

• Schwinger  $\leftrightarrow$  Im  $\epsilon \leftrightarrow$  Re  $\epsilon \Rightarrow \epsilon$  as an indirect signature of Schwinger & vice versa



### **Peak value**

#### **Behaviors of the peaks**



Numerical fit says (similar numbers for Im  $\epsilon_{\perp}$  and Re  $\epsilon_{\parallel,\perp}$ )

$$
\text{Re }\Delta\epsilon_{\parallel} \approx (-1.4 \times 10^{-4}) \times \left(\frac{I}{1 \times 10^{23} \text{ W/cm}^2}\right)^{0.19} \text{ where } I = \bar{E}^2 / 2 \text{ is the focused intensity}
$$

• much larger than EH e.g.,  $\Delta \epsilon_{\text{EH}} = O(10^{-7})$  for  $I = O(1 \times 10^{23} \text{ W/cm}^2)$  (PW laser)

 $\Rightarrow$  High-frequency probe is useful to study  $\epsilon$  (or vacuum birefringence, in general)

• weak E dependence  $\Delta \epsilon \propto I$ 1  $\frac{1}{5} \sim \frac{1}{6}$  $\overline{6}$   $\Rightarrow$  the peaks of  $\Delta \epsilon$  can still be large for subcritical fields

e.g., only one-order smaller  $\Delta \epsilon = O(1 \times 10^{-5}) \gg \Delta \epsilon_{\text{EH}}$  at GW scale